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74LCX02

General Description

The LCX02 contains four 2-input NOR gates. The inputs tolerate voltages up to 5.5 V allowing the interface of 5 V systems to 3 V systems.

The 74LCX02 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5 V Tolerant Inputs
- 1.65 V 5.5 V V_{CC} Specifications Provided
- 5.2 ns t_{PD} Max. (V_{CC} = 3.3 V)
- 10 µA I_{CC} Max.
- Power Down High Impedance Inputs and Outputs
- ± 24 mA Output Drive (V_{CC} = 3.0 V)
- Implements Proprietary Noise/EMI Reduction Circuitry
- Latch-up Performance Exceeds 100 mA
- ESD Performance:
 - Human Body Model > 2000 V
- This Device is Pb-Free, Halide Free and RoHS Compliant

Logic Symbol

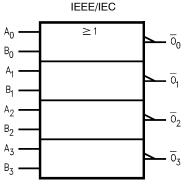


Figure 1. Logic Symbol

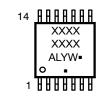
PIN DESCRIPTION

Pin Name	Description
A _n , B _n	Inputs
Ōn	Outputs



TSSOP-14 WB CASE 948G

MARKING DIAGRAMS



XXXXXX = Specific Device Code A = Assembly Location

- = Assembly Lo = Wafer Lot
- = Water = Year

L Y

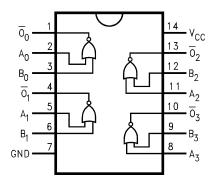
W

-

- = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

DATA SHEET www.onsemi.com

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ABSOLUTE MAXIMUM RATINGS

Symbol	Pi	arameter	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
VI	DC Input Voltage (Note 1)		-0.5 to +6.5	V
Vo	DC Output Voltage (Note 1)	Active-Mode (High or Low State)	–0.5 to V _{CC} + 0.5	V
		Tri-State Mode	-0.5 to +6.5	V
		Power-Down Mode (V _{CC} = 0 V)	-0.5 to +6.5	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
Ι _{ΟΚ}	DC Output Diode CurrentD	V _O < GND	-50	mA
Ι _Ο	DC Output Source / Sink Current	±50	mA	
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or C	±100	mA	
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for	or 10 secs	260	°C
Τ _J	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)		150	°C/W
PD	Power Dissipation in Still Air at 125 °C		833	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V
		Charged Device Model	N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.

 Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Тур	Max	Unit
V _{CC}	Supply Voltage	oply Voltage Operating		3.3	5.5	V
		Data Retention Only	1.5	3.3	5.5	
VI	Digital Input Voltage	-	0	-	5.5	V
Vo	Output Voltage	Active Mode (High or Low State)	0	-	V _{CC}	V
		Tri-State Mode	0	-	5.5	
		Power Down Mode ($V_{CC} = 0 V$)	0	-	5.5	
T _A	Operating Free-Air Temperature	-	-40	-	+125	°C
t _r , t _f	Input Rise or Fall Rate	V _{CC} = 1.65 V to 1.95 V	0	-	20	nS/V
		V_{CC} = 2.3 V to 2.7 V	0	-	20	
		$V_{\rm I}$ from 0.8 V to 2.0 V, V_{CC} = 3.0 V	0	-	10	
		V_{CC} = 4.5 V to 5.5 V	0	-	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

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DC ELECTRICAL CHARACTERISTICS

				T _A = -40 °C	C to +85 °C	T _A = -40 °C	to +125 °C	
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage		1.65 – 1.95	$0.65 \times V_{CC}$	-	$0.65 \times V_{CC}$	-	V
			2.3 – 2.7	1.7	-	1.7	-	
			3.0 - 3.6	2.0	-	2.0	-	
			4.5 – 5.5	$0.70 \times V_{CC}$	-	0.70 x V _{CC}	-	
V _{IL}	LOW Level Input Voltage		1.65 – 1.95	-	0.35 x V _{CC}	-	0.35 x V _{CC}	V
			2.3 – 2.7	-	0.7	-	0.7	
			3.0 - 3.6	-	0.8	-	0.8	
			4.5 – 5.5	-	$0.30 \times V_{CC}$	-	$0.30 \times V_{CC}$	
V _{OH}	High-Level Output Voltage Low-Level Output Voltage	$ \begin{array}{l} V_{I} = V_{IH} \mbox{ or } V_{IL} \\ I_{OH} = -100 \ \mu A \\ I_{OH} = -4 \ m A \\ I_{OH} = -8 \ m A \\ I_{OH} = -12 \ m A \\ I_{OH} = -16 \ m A \\ I_{OH} = -24 \ m A \\ I_{OH} = -32 \ m A \\ \hline V_{I} = V_{IH} \ m V_{IL} \\ I_{OL} = 100 \ \mu A \\ I_{OL} = 4 \ m A \\ I_{OL} = 8 \ m A \\ I_{OL} = 8 \ m A \\ I_{OL} = 12 \ m A \end{array} $	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5 1.65 to 5.5 1.65 2.3 2.7	V _{CC} - 0.1 1.29 1.8 2.2 2.4 2.2 3.7	- - - - - - - - - - - - - - - - - - -	V _{CC} - 0.1 1.29 1.8 2.2 2.4 2.2 3.7	- - - - - - - - - - - - - - - - - - -	V
	Input Leakage Current	$I_{OL} = 12 \text{ mA}$ $I_{OL} = 16 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 32 \text{ mA}$ $V_{I} = 0 \text{ to } 5.5 \text{ V}$	2.7 3.0 3.0 4.5 1.65 - 5.5	- - - -	0.4 0.4 0.55 0.6 ±5.0	- - - -	0.4 0.4 0.55 0.6 ±5.0	μΑ
I _{OFF}	Power Off Leakage	V _I = 5.5 V or	0	_	10	_	10	μA
	Current	V _O = 5.5 V						¥ .
I _{CC}	Quiescent Supply Current	V _I = 5.5 V or GND	1.65 – 5.5	-	10	-	10	μA
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6 V$	2.3 to 3.6	-	500	-	500	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

				T _A = -40 °	C to +85 °C	T _A = -40 °C	to +125 °C												
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Max	Min	Max	Unit											
t _{PLH} ,	Propagation Delay,	See Figure 2	1.65 – 1.95	-	10.3	-	10.3	ns											
τρηΓ	t _{PHL} Input to Output	and Figure 3	2.3 – 2.7	-	6.2	-	6.2												
			2.7	-	6.0	-	6.0												
															3.0 – 3.6	-	5.2	-	5.2
			4.5 – 5.5	_	4.2	-	4.2												
t _{OSHL} ,	Output to Output Skew		1.65 – 1.95	-	-	-	-	ns											
toslh				2.3 – 2.7	_	-	-	-											
			2.7	_	-	-	-												
					3.0 – 3.6	_	1.0	-	1.0										
			4.5 – 5.5	_	-	-	-												

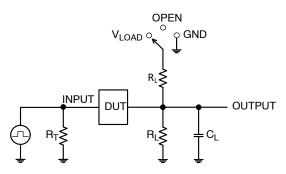
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DYNAMIC SWITCHING CHARACTERISTICS

				T _A = 25 °C	
Symbol	Parameter	V _{CC} (V)	Condition	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V	0.8	V
		2.5	C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V	0.6	
V _{OLV}	Quiet Output Dynamic Valley V_{OL}	3.3	C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V	-0.8	V
		2.5	$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	-0.6	

CAPACITANCE

Symbol	Parameter	Condition	Тур	Unit
C _{IN}	Input Capacitance	V_{CC} = Open, V_{I} = 0 V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC},f = 10 MHz	25	pF



V_n

Test	Switch Position
t _{PLH} / t _{PHL}	Open
t _{PLZ} / t _{PZL}	V _{LOAD}
t _{PHZ} / t _{PZH}	GND

 C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 $\Omega)$ f = 1 MHz

10%

tрн

 t_{PLH}

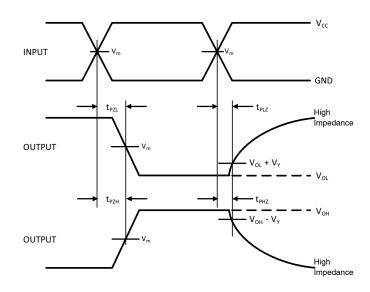
V,

t_r = 2.5 ns

INPUT

OUTPUT

OUTPUT



Lique	` 2	Toot	Circuit
Flaure	22.	lest	Circuit

t_f = 2.5 ns

10%

٧...

Vm

t_{PLH}

 t_{PHL} Þ

Vcc

GND

V_{OH}

Vo

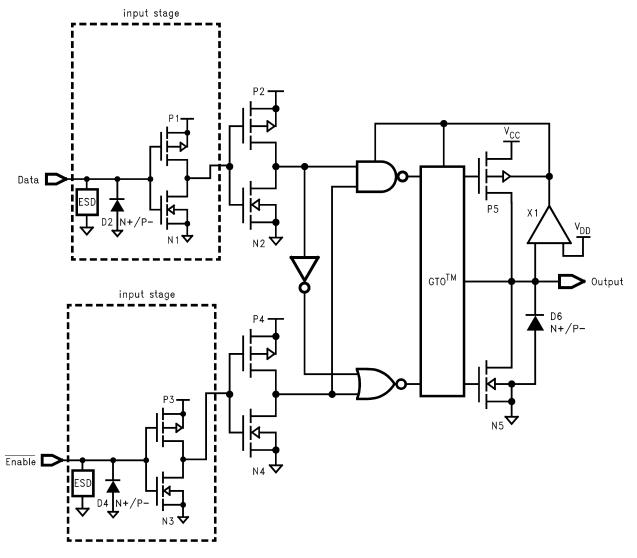
V_{OH}

 V_{OL}

V _{CC} , V	R_{L}, Ω	C _L , pF	V _{LOAD}	V _m , V	V _Y , V
1.65 to 1.95	500	30	$2 \times V_{CC}$	V _{CC} /2	0.15
2.3 to 2.7	500	30	$2 \times V_{CC}$	V _{CC} /2	0.15
2.7	500	50	6 V	1.5	0.3
3.0 to 3.6	500	50	6 V	1.5	0.3
4.5 to 5.5	500	50	$2 \times V_{CC}$	V _{CC} /2	0.3

Figure 3. Switching Waveforms

Schematic Diagram (Generic for LCX Family)



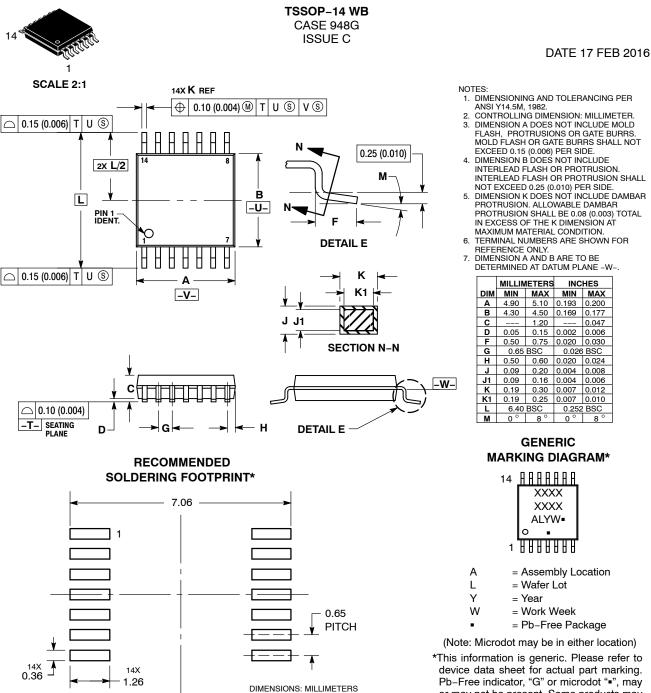


ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74LCX02MTCX	LCX 02	TSSOP-14 (Pb-Free, Halide Free)	2500 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT
- INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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